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Si4544DY
Vishay Siliconix

N- and P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY

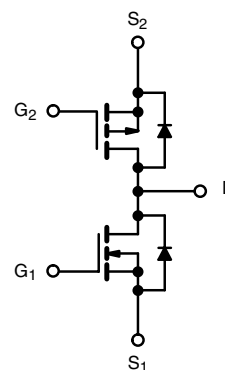
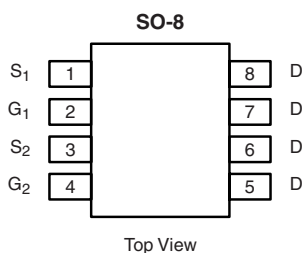
	V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)
N-Channel	30	0.035 at V _{GS} = 10 V	± 6.5
		0.050 at V _{GS} = 4.5 V	± 5.4
P-Channel	- 30	0.045 at V _{GS} = - 10 V	± 5.7
		0.090 at V _{GS} = - 4.5 V	± 4.0

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC



RoHS
COMPLIANT
HALOGEN
FREE
Available



Ordering Information: Si4544DY-T1-E3 (Lead (Pb)-free)
Si4544DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS T_A = 25 °C, unless otherwise noted

Parameter		Symbol	N-Channel	P-Channel	Unit
Drain-Source Voltage		V _{DS}	30	- 30	V
Gate-Source Voltage		V _{GS}	± 20	± 20	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	I _D	± 6.5	± 5.7	A
	T _A = 70 °C		± 5.4	± 4.0	
Pulsed Drain Current		I _{DM}	± 20	± 20	
Continuous Source Current (Diode Conduction) ^a		I _S	1.7	- 1.7	
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	2.4		W
	T _A = 70 °C		1.5		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	N- or P-Channel	Unit
Maximum Junction-to-Ambient ^a	R _{thJA}	52	°C/W

Notes:

a. Surface Mounted on FR4 board, t ≤ 10 s.

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions		Min.	Typ.	Max.	Unit
Static							
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	N-Ch	1.0			V
		V _{DS} = V _{GS} , I _D = - 250 μA	P-Ch	- 1.0			
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	N-Ch P-Ch			± 100 ± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	N-Ch			1	μA
		V _{DS} = - 30 V, V _{GS} = 0 V	P-Ch			- 1	
		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C	N-Ch			5	
		V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 55 °C	P-Ch			- 5	
On-State Drain Current ^a	I _{D(on)}	V _{DS} ≥ 5 V, V _{GS} = 10 V	N-Ch	20			A
		V _{DS} ≥ - 5 V, V _{GS} = - 10 V	P-Ch	- 20			
		V _{DS} ≥ 5 V, V _{GS} = 4.5 V	N-Ch	5			
		V _{DS} ≥ - 5 V, V _{GS} = - 4.5 V	P-Ch	- 5			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 6.5 A	N-Ch		0.027	0.035	Ω
		V _{GS} = - 10 V, I _D = - 5.7 A	P-Ch		0.036	0.045	
		V _{GS} = 4.5 V, I _D = 5.4 A	N-Ch		0.038	0.050	
		V _{GS} = - 4.5 V, I _D = - 4.0 A	P-Ch		0.060	0.090	
Forward Transconductance ^a	g _{fs}	V _{DS} = 15 V, I _D = 6.5 A	N-Ch		15		S
		V _{DS} = - 15 V, I _D = - 5.7 A	P-Ch		9		
Diode Forward Voltage ^a	V _{SD}	I _S = 1.7 A, V _{GS} = 0 V	N-Ch		0.75	1.2	V
		I _S = - 1.7 A, V _{GS} = 0 V	P-Ch		- 0.75	- 1.2	
Dynamic ^b							
Total Gate Charge	Q _g	N-Channel V _{DS} = 15 V, V _{GS} = 10 V, I _D = 6.5 A	N-Ch P-Ch		18 19	35 40	nC
Gate-Source Charge	Q _{gs}		N-Ch P-Ch		4.2 4.5		
Gate-Drain Charge	Q _{gd}	P-Channel V _{DS} = - 15 V, V _{GS} = - 10 V, I _D = - 5.7 A	N-Ch P-Ch		3.5 3.6		
Turn-On Delay Time	t _{d(on)}	N-Channel V _{DD} = 15 V, R _L = 15 Ω I _D ≅ 1 A, V _{GEN} = 10 V, R _g = 6 Ω	N-Ch P-Ch		13 13	30 30	ns
Rise Time	t _r		N-Ch P-Ch		12 15	30 30	
Turn-Off Delay Time	t _{d(off)}	P-Channel V _{DD} = - 15 V, R _L = 15 Ω I _D ≅ - 1 A, V _{GEN} = - 10 V, R _g = 6 Ω	N-Ch P-Ch		31 37	60 70	
Fall Time	t _f		N-Ch P-Ch		10 14	30 30	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dI/dt = 100 A/μs	N-Ch		30	70	
		I _F = - 1.7 A, dI/dt = 100 A/μs	P-Ch		35	70	

Notes:

a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

b. Guaranteed by design, not subject to production testing.

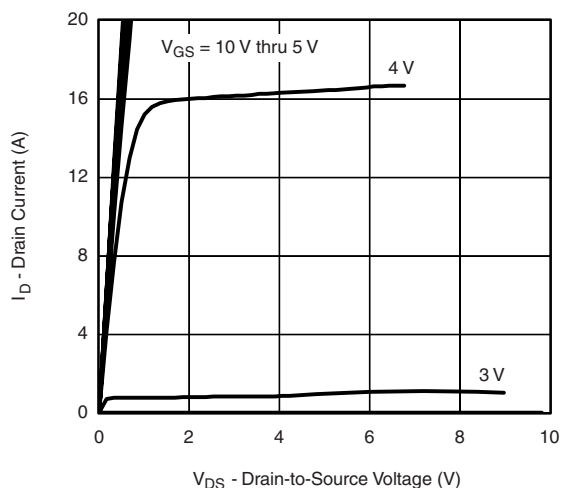
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



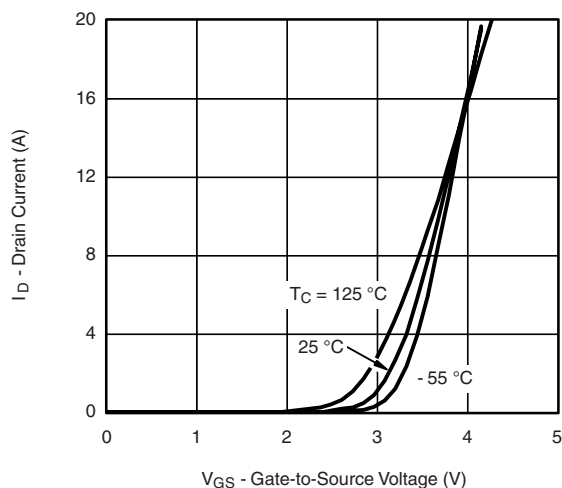
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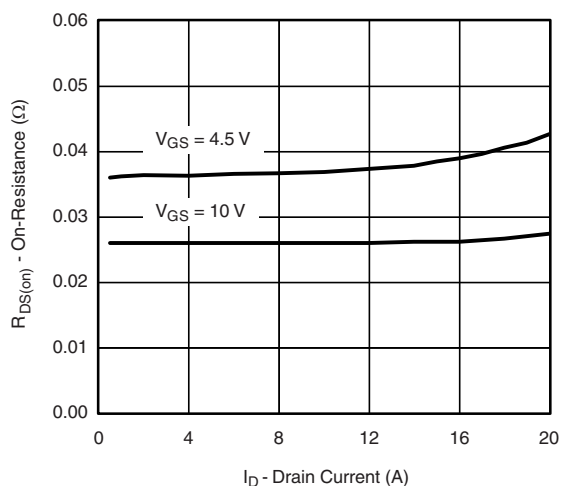
N-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



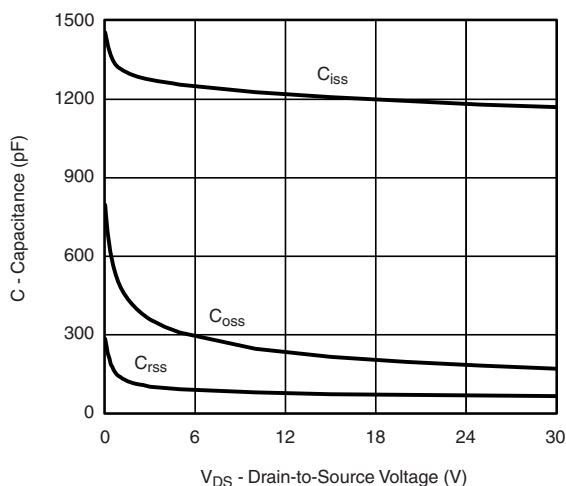
Output Characteristics



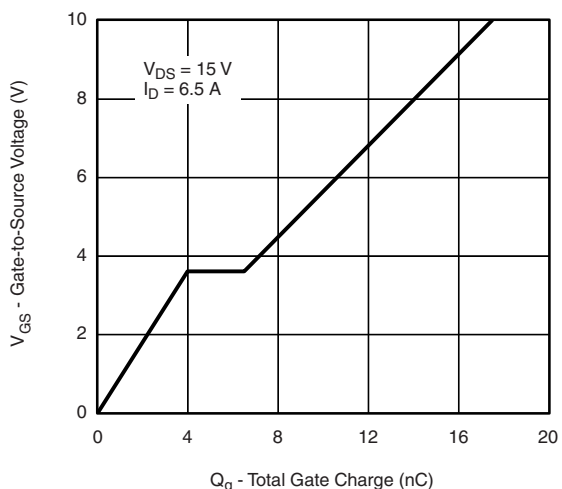
Transfer Characteristics



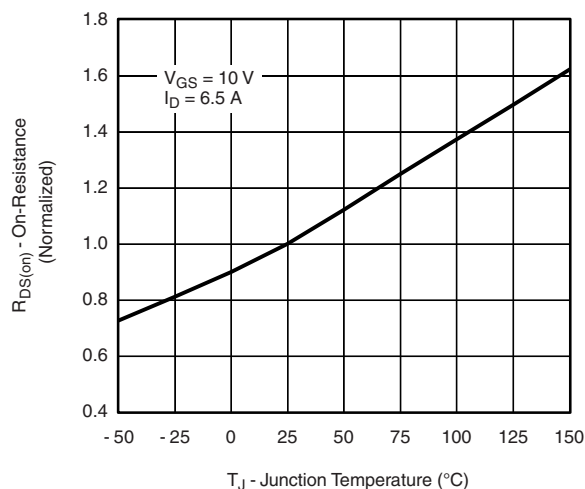
On-Resistance vs. Drain Current



Capacitance



Gate Charge



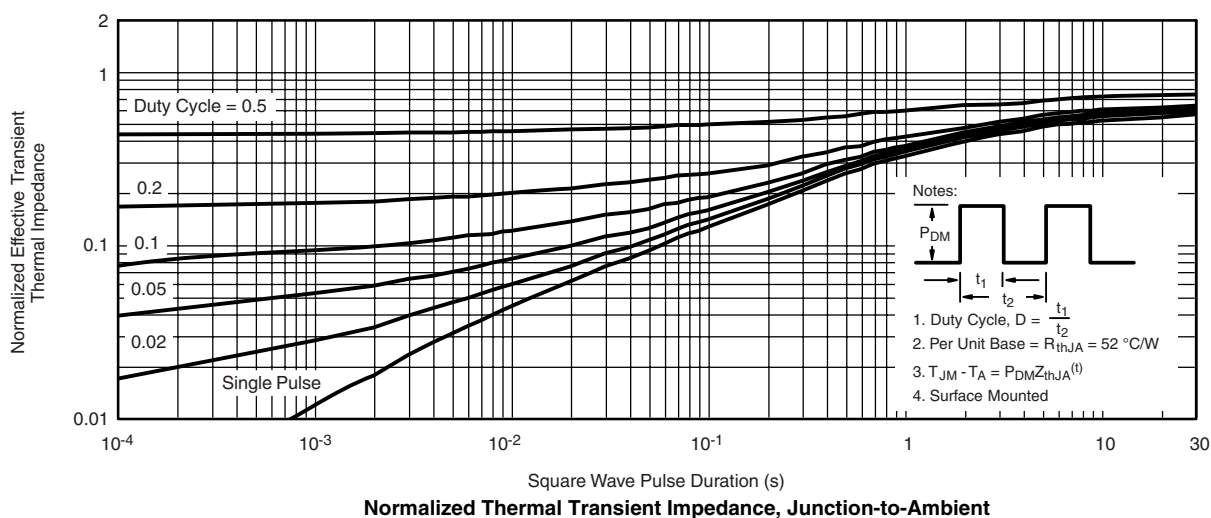
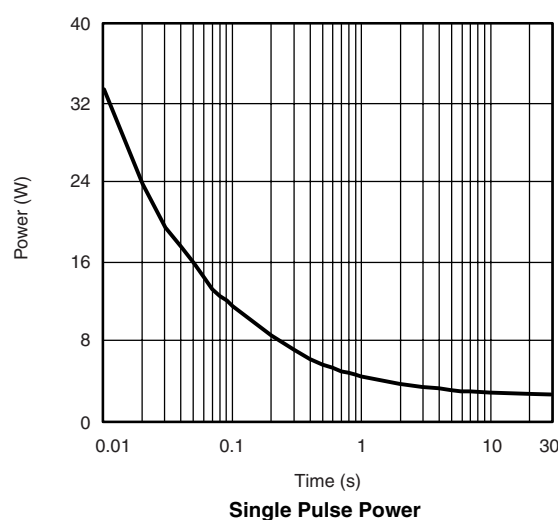
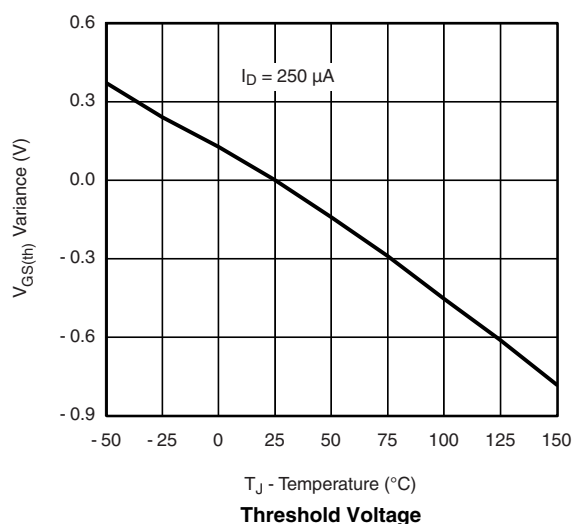
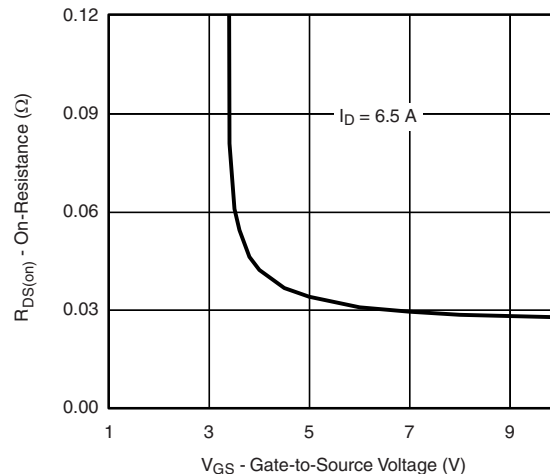
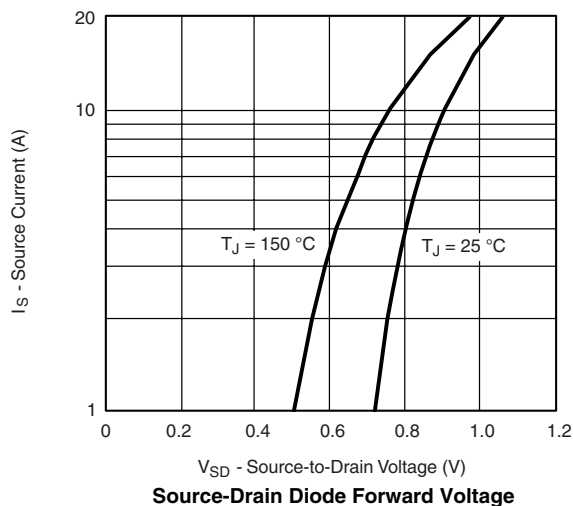
On-Resistance vs. Junction Temperature

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N-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted

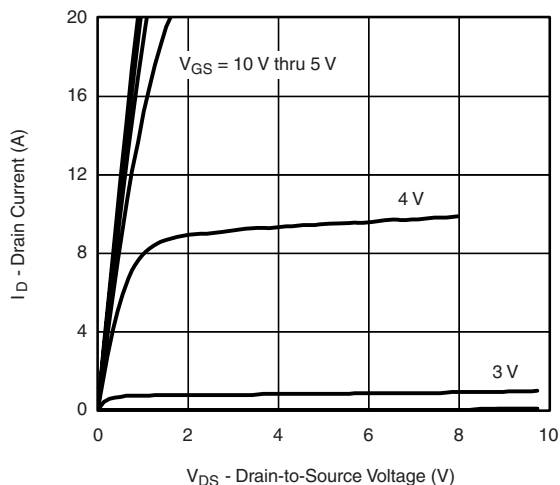




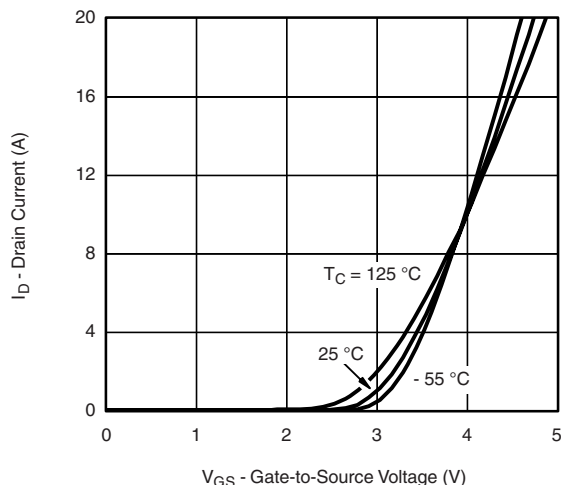
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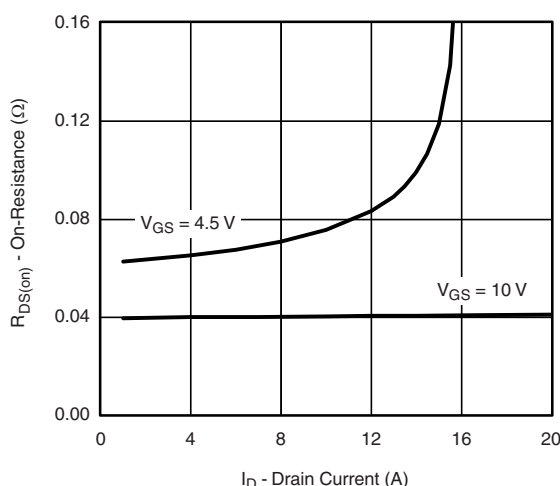
P-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



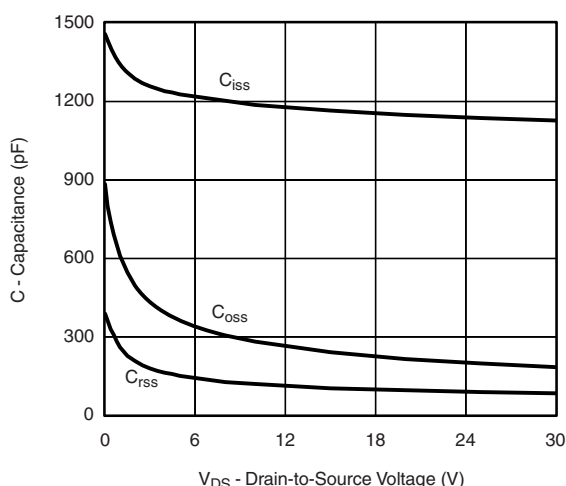
Output Characteristics



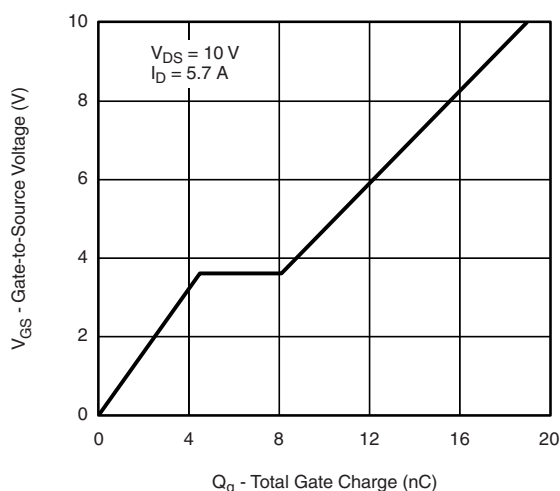
Transfer Characteristics



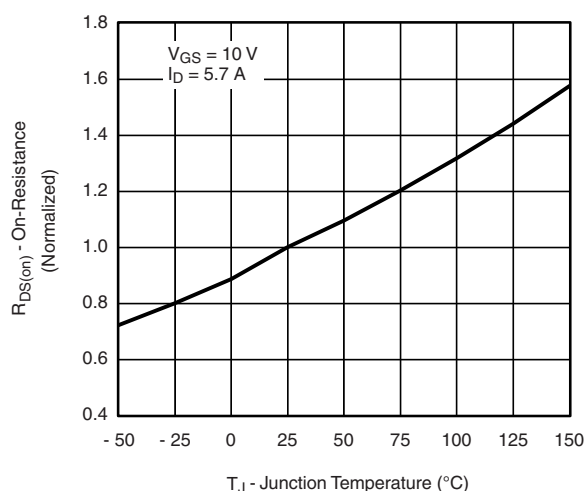
On-Resistance vs. Drain Current



Capacitance



Gate Charge



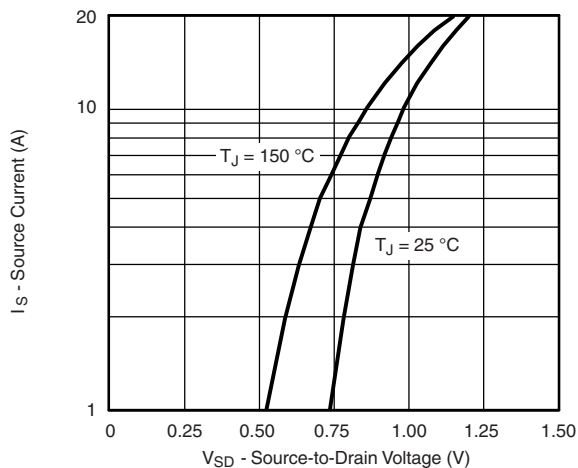
On-Resistance vs. Junction Temperature

Si4544DY

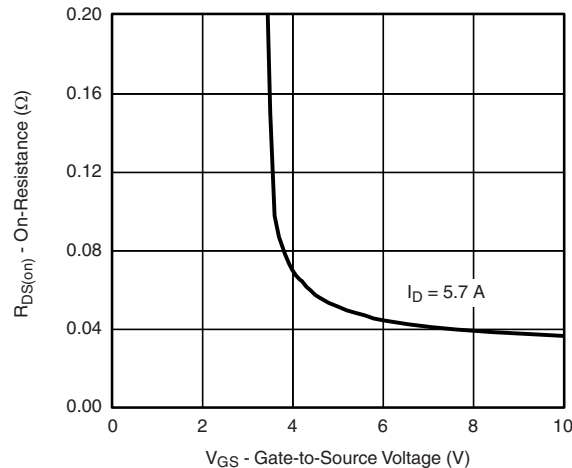
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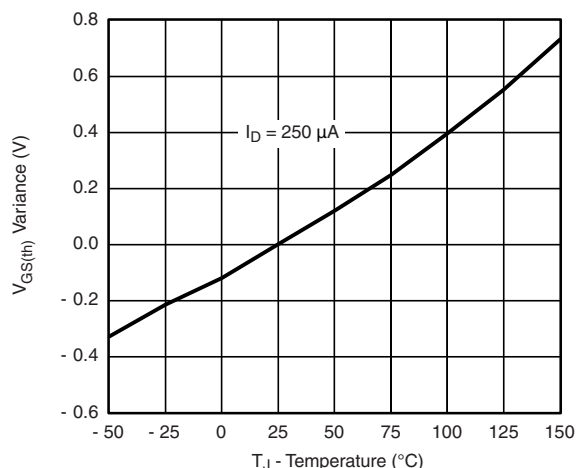
P-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



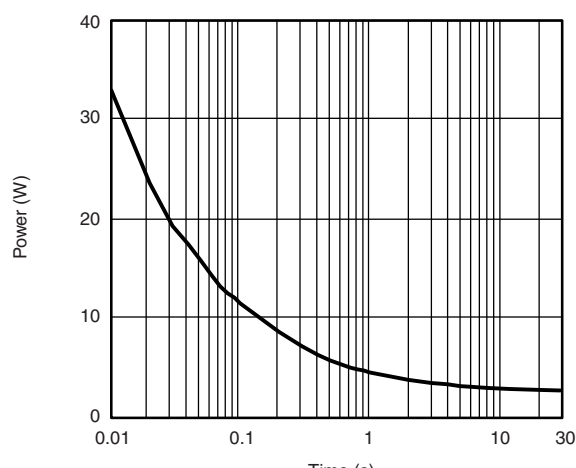
Source-Drain Diode Forward Voltage



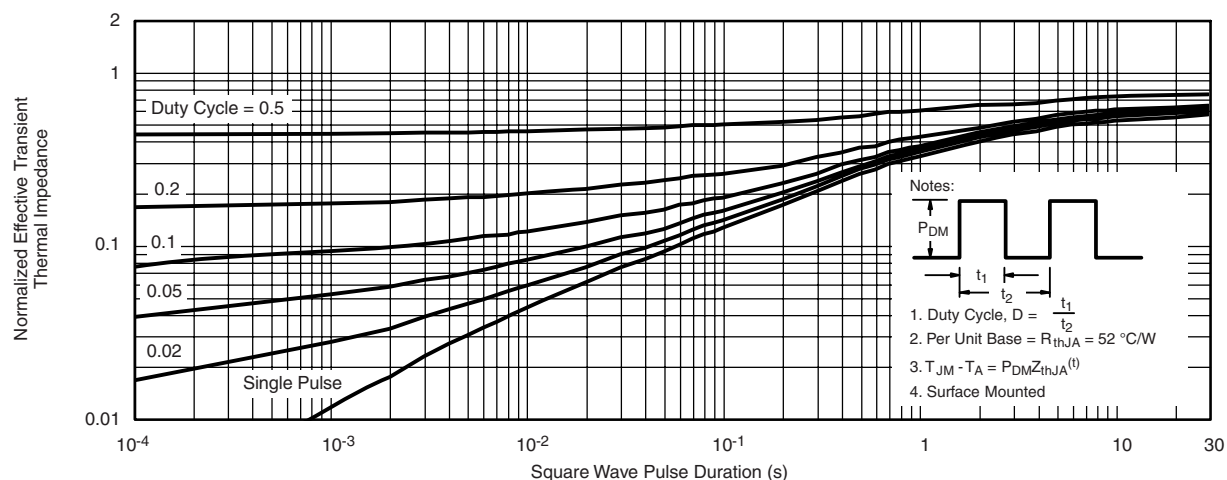
On-Resistance vs. Junction Temperature



Threshold Voltage



Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg770768.



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